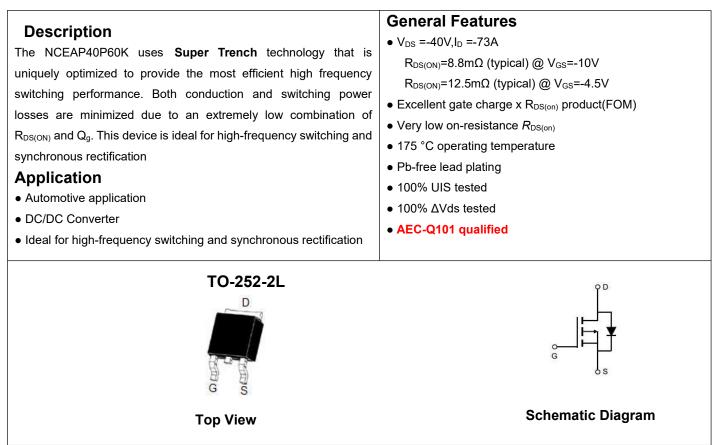


NCE P-Channel Super Trench Power MOSFET



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|-------------|----------------|-----------|------------|----------|
| AP40P60K | NCEAP40P60K | TO-252-2L | - | - | - |

Absolute Maximum Ratings (Tc=25[°]C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|----------------------------------|------------|------|
| Drain-Source Voltage | Vds | -40 | V |
| Gate-Source Voltage | Vgs | ±20 | V |
| Drain Current-Continuous ^(Note1) | ID | -73 | A |
| Drain Current-Continuous(Tc=100℃) | I₀ (Tc=100℃) | -52 | A |
| Pulsed Drain Current | I _{DM} | -240 | A |
| Maximum Power Dissipation(T_c=25 $^\circ\!\mathrm{C}$) | P₀(Tc=25℃) | 110 | W |
| Derating factor | | 0.64 | W/°C |
| Single pulse avalanche energy (Note 2) | Eas | 352 | mJ |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 175 | °C |

Thermal Characteristic

| Thermal Resistance, Junction-to-CaseR _{0JC} 1.36°C/W |
|---|
|---|



Electrical Characteristics (Tc=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|--|------|------|------|------|
| Off Characteristics | · · · | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250µA | -40 | | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-40V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | Igss | V _{GS} =±20V,V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics | i | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=-250\mu A$ | -1.0 | -1.7 | -2.5 | V |
| | | V _{GS} =-10V, I _D =-20A | - | 8.8 | 11.0 | mΩ |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =-4.5V, I _D =-20A | - | 12.5 | 17.0 | mΩ |
| Forward Transconductance | g fs | V _{DS} =-5V,I _D =-20A | - | 30 | - | S |
| Dynamic Characteristics | · · · | | | | | |
| Input Capacitance | Clss | | - | 2450 | - | PF |
| Output Capacitance | Coss | V_{DS} =-20V, V_{GS} =0V, | - | 660 | - | PF |
| Reverse Transfer Capacitance | Crss | F=1.0MHz | - | 18 | - | PF |
| Switching Characteristics (Note 1) | | | | | | 1 |
| Turn-on Delay Time | t _{d(on)} | | - | 9 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =-20V,I _D =-20A | - | 4 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V _{GS} =-10V,R _G =1.6Ω | - | 30 | - | nS |
| Turn-Off Fall Time | t _f | | - | 5 | - | nS |
| Total Gate Charge | Qg | N/ 001/1 00A | - | 39 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =-20V,I _D =-20A, | - | 7.8 | | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =-10V | - | 5.3 | | nC |
| Drain-Source Diode Characteristics | | | 1 | | | |
| Diode Forward Voltage | V _{SD} | V _{GS} =0V,I _S =-20A | - | | -1.2 | V |
| Diode Forward Current | ls | | - | - | -60 | Α |
| Reverse Recovery Time | t _{rr} | T _J = 25°C, I _F =-20A | - | 22 | | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs | - | 58 | | nC |

Notes:

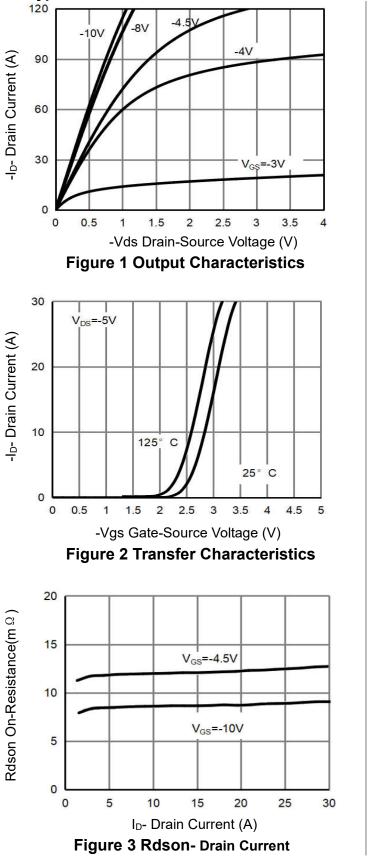
1. Defined by design.Not Subject to production test

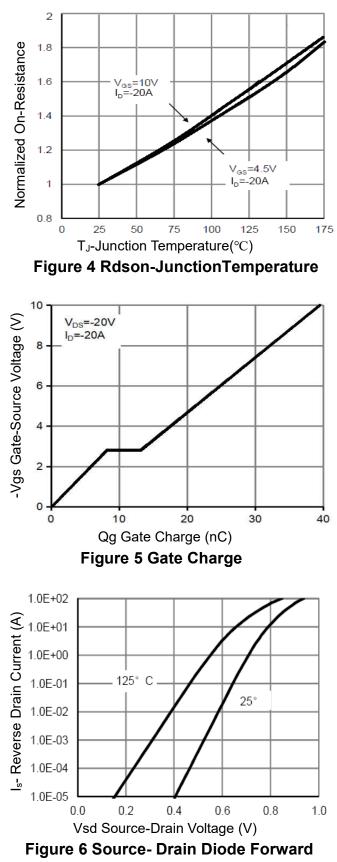
2. EAS condition : Tj=25 $^\circ C$, V_DD=-20V , V_G=-10V , L=0.5mH , Rg=25\Omega

3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.











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NCEAP40P60K

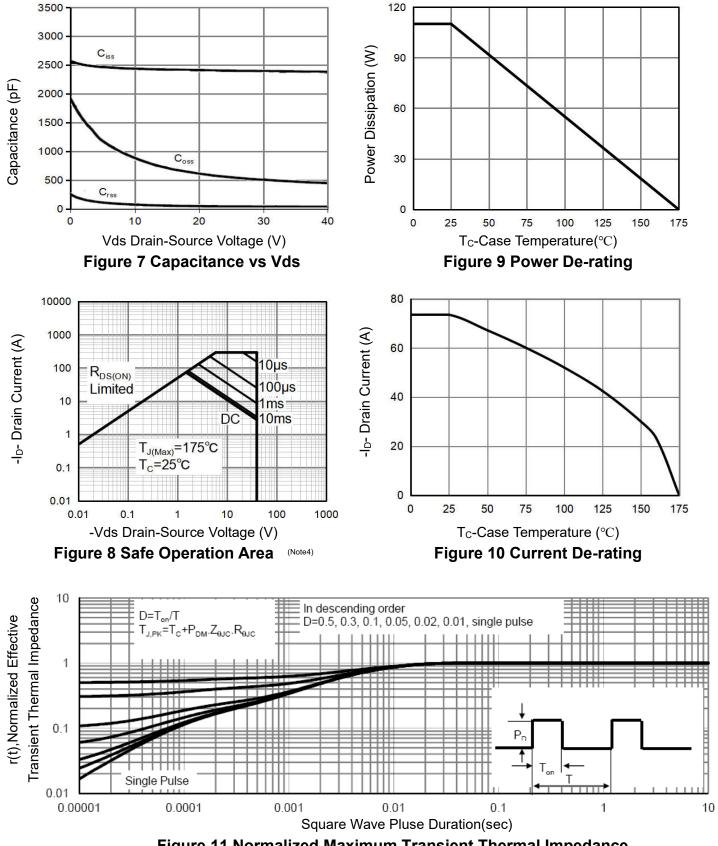


Figure 11 Normalized Maximum Transient Thermal Impedance

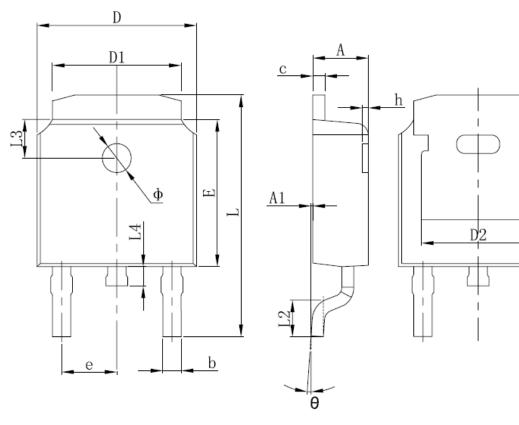


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Ι

TO-252-2L Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|--------|----------------------|-------|--|
| Symbol | Min. | Max. | Min. | Max. | |
| A | 2.200 | 2.400 | 0.087 | 0.094 | |
| A1 | 0.000 | 0.127 | 0.000 | 0.005 | |
| b | 0.635 | 0.770 | 0.025 | 0.030 | |
| с | 0.460 | 0.580 | 0.018 | 0.023 | |
| D | 6.500 | 6.700 | 0.256 | 0.264 | |
| D1 | 5.100 | 5.460 | 0.201 | 0.215 | |
| D2 | 4.830 | REF. | 0.190 REF. | | |
| E | 6.000 | 6.200 | 0.236 | 0.244 | |
| е | 2.186 | 2.386 | 0.086 | 0.094 | |
| L | 9.712 | 10.312 | 0.382 | 0.406 | |
| L1 | 2.900 REF. | | 0.114 REF. | | |
| L2 | 1.400 | 1.700 | 0.055 | 0.067 | |
| L3 | 1.600 | REF. | 0.063 REF. | | |
| L4 | 0.600 | 1.000 | 0.024 | 0.039 | |
| Φ | 1.100 | 1.300 | 0.043 | 0.051 | |
| θ | 0° | 8° | 0° | 8° | |
| h | 0.000 | 0.300 | 0.000 | 0.012 | |
| V | 5.250 REF. 0.207 REF. | | | REF. | |



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